# Ceramic, Hermetic SPDT RF Switch

Absorptive RF Switch with internal driver. Single Supply Voltage, +3V to +5V

#### **Product Features**

- Wide bandwidth, 500 to 6000 MHz
- High Isolation, 65 dB typ. at 1 GHz
- Low insertion loss, 1.0 dB typ.
- Internal CMOS driver
- Fast switching, Rise/fall time, 30 ns typ.
- Built rugged for tough environments
- Hermetically sealed
- Wide operating temperature, -55°C to 125°C

#### **Typical Applications**

- Automated switching networks
- Cellular
- PCN
- ISM, WCDMA, WIMAX
- Military

#### **General Description**





## CSWA2-63DR+

CASE STYLE: DG1293

MIL screening available Please consult Applications Dept.

+RoHS Compliant The +Suffix identifies RoHS Compliance. See our web site for RoHS Compliance methodologies and qualifications

The CSWA2-63DR+ is a 50 $\Omega$  high isolation, absorptive SPDT RF switch designed for wireless applications, covering a broad frequency range from 500 to 6000 MHz with low insertion loss. In non absorptive mode, the switch is usable down to 0.3 MHz. It may also be used in 75 $\Omega$  systems over 0.3-3000 MHz. The CSWA2-63DR+ operates on a single supply voltage in the range of +3V to +5V. This unit includes an internal CMOS driver. The CSWA2-63DR+ switch comes in a low profile hermetic very small size package, 4mm x 4mm x 1.2mm. Expected MTBF is 373 years at 85°C case temperature. This switch is capable of meeting MIL requirements for gross leak, fine leak, thermal shock, vibration, acceleration, mechanical shock, and HTOL. The testing can be done if requested.

Schematic and Application Circuit



Cblock should be free of resonance over frequency of operation.

Frequency (MHz)	Cblock (Suggested value)
0.3-500	0.1µF
500-6000	47pF

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Parameter		Min.	Тур.	Max.	Units
Frequency Range		500		6000	MHz
	0.3 to 500 MHz		1.0		
	500 to 2000 MHz		1.0	1.3	
Insertion Loss	2000 to 3000 MHz		1.1	1.4	dD
	3000 to 4000 MHz		1.2	1.5	aв
	4000 to 6000 MHz		1.5	1.8	
	0.3 to 500 MHz	—	60		
	500 to 2000 MHz	50	60		
Isolation between Common port and RF1/RF2 Ports	2000 to 3000 MHz	47	52		dD
	3000 to 4000 MHz	45	50		uв
	4000 to 6000 MHz	40	44		
	0.3 to 500 MHz	—	70		
	500 to 2000 MHz	52	60		
Isolation between RF1 and RF2 ports	2000 to 3000 MHz	47	52		JD
	3000 to 4000 MHz	44	50		dB
	4000 to 6000 MHz	36	44		
	0.3 to 500 MHz		20		
	100 to 2000 MHz		20		
	2000 to 3000 MHz		15		dB
Return Loss (ON STATE)	3000 to 4000 MHz		15		
	4000 to 6000 MHz		15		
	500 to 2000 MHz		13		
	2000 to 3000 MHz		13		-ID
Return Loss @ RF1/RF2 ports (OFF STATE)	3000 to 4000 MHz		14		dB
	4000 to 6000 MHz		14		
	V <sub>DD</sub> =3V, 500 to 2000 MHz		47		
Input IP3	2000 to 6000 MHz		40		
	V <sub>DD</sub> =5V, 500 to 2000 MHz		50		dBm
	2000 to 6000 MHz		45		
	Vpp=3V. 500 to 2000 MHz		24		
	2000 to 6000 MHz		24		
Input 1dB Compression <sup>(2)</sup>	Vpp=5V, 500 to 2000 MHz		30		dBm
	2000 to 6000 MHz		27		

#### RF Electrical Specifications<sup>(1)</sup>, 500 - 6000 MHz, T<sub>AMP</sub>=25°C, V<sub>DD</sub>= +3V to +5V

#### **DC Electrical Specifications**

Parameter	Min.	Тур.	Max.	Units
VDD, Supply Voltage	3		5	V
Supply Current $(V_{DD} = 5V)^{(3)}$		50		μA
Control Voltage Low	0		0.5	V
Control Voltage High <sup>(4)</sup>	2.7(5)		V <sub>DD</sub>	V
Control Current		5		μA
Notes:				

1. Insertion loss values are deembedded from test board loss. Tested using Agilent's N5230A network analyzer with internal DC blocks,

except for IP3 and compression. 2. Note absolute maximum rating for input and dissipated power. At 5V, over 2000-6000 MHz, 0.2 dB compression.

2. Increases with switching repetition rate. See graph. 4. CMOS interface latch-up condition may occur when logic high signal is applied prior to power supply. 5. 3.5V for  $V_{DD}$ =4 to 5V

#### Switching Specifications at V<sub>DD</sub>=5V

Parameter	Min.	Тур.	Max.	Units
Rise/Fall Time (10 to 90% or 90 to 10% RF)		23		nSec
Switching Time (50% CTRL to 90/10% RF)		35		nSec
Video Feedthrough (Control 0-5V, Frequency 1 MHz)		25		$mV_{P-P}$

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#### **Absolute Maximum Ratings**

Parameter	Ratings	
Operating Temperature	-55°C to 125°C	
Storage Temperature	-65°C to 150°C	
V <sub>DD</sub> , Supply Voltage	2.7 to 5.5V	
Voltage Control	-0.2V Min. V <sub>DD</sub> Max.	
RF input power	1Watt	
Dissipated Power at 25°C	370mW	
ESD, HBM	Class 1A (250 to <500V) per JESD22-A114	
ESD, MM	Class A (passes 50V) per JESD22-A115	
ESD, CDM	Class III (500 to <1000V) per JESD22-C101	

#### Truth Table (State of control voltage selects the desired switch state)

State of Control Voltage	Switch State - RF Common to		
	RF1	RF2	
Low	ON	OFF	
High	OFF	ON	
ON- low insertion loss state OFF- Isolation State			

#### **Pad Connections**

Function	Pad Number	Description
RF COM	15	RF Common/ SUM Port
RF1	4	RF Out #1/In Port #1
RF2	9	RF Out #1/In Port #2
Control	13	CMOS Control IN
VDD	12	Supply Voltage
GND	1,2,3,5,6,7,8,10, 11,14,16, paddle	RF Ground

#### Pad Configuration (Top View)



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#### **Product Marking**



#### **Additional Detailed Technical Information**

Additional information is available on our web site. To access this information enter the model number on our web site home page.

#### Performance data, graphs

Case Style: DG1293 Ceramic, finish: gold over nickel

Tape & Reel: F70Standard quantities available on reel: 7" reels with 20, 50, 100, 200, 500, 1K devices.13" reels with 2K devices.

Suggested Layout for PCB Design: PL-279

**Evaluation Board: TB-461+** 

**Environmental Ratings: ENV40** 

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